



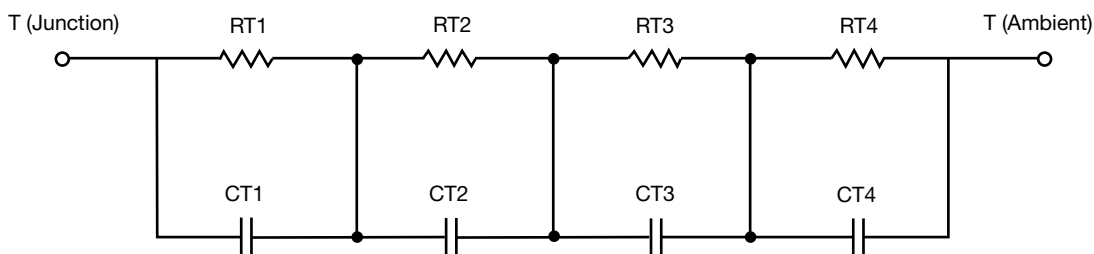
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	3.9825	27.7226m	n/a
RT2	12.2711	713.3935m	n/a
RT3	12.0294	371.3819m	n/a
RT4	34.7170	787.5020m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	2.3119m	1.2136	n/a
CT2	30.1723m	2.6726m	n/a
CT3	967.3709m	501.3570u	n/a
CT4	2.6154	8.2039m	n/a

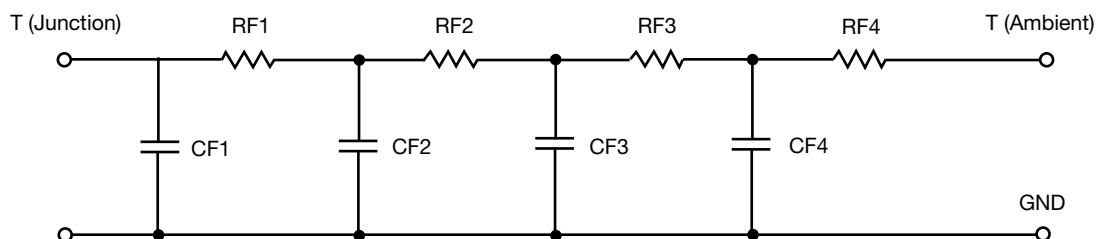
Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	7.5244	646.1041m	n/a
RF2	11.4303	718.2059m	n/a
RF3	20.8012	396.7723m	n/a
RF4	23.2441	139.8980m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	4.2657m	461.4443u	n/a
CF2	51.1875m	2.2484m	n/a
CF3	813.7653m	2.4743m	n/a
CF4	2.9288	70.0384m	n/a

Note

- n/a indicates not applicable

